

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>		<i>Complete if Known</i> Application Number Unknown Filing Date Even Date Herewith First Named Inventor Moradi, Behnam Group Art Unit Unknown Examiner Name Ramsey, Kenneth	
Sheet 1 of 2		Attorney Docket No: 303.591US2	

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Sheet 2 of 2		Attorney Docket No: 303.591US2	

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